Group 13 β -Ketoiminate Compounds: Gallium Hydride Derivatives As Molecular Precursors to Thin Films of $Ga₂O₃$

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S Supporting Information

[ABSTRACT:](#page-9-0) Bis(β -ketoimine) ligands, $[R\{N(H)C(Me)\}$ - $CHC(Me) = O_{2}$] $(L_{1}H_{2}, R = (CH_{2})_{2}; L_{2}H_{2}, R = (CH_{2})_{3}),$ linked by ethylene (L_1) and propylene (L_2) bridges have been used to form aluminum, gallium, and indium chloride complexes $[Al(L_1)Cl]$ (3), $[Ga(L_n)Cl]$ (4, $n = 1$; 6, $n = 2$) and $\left[\text{In}(L_n)C\right]$ (5, n = 1; 7, n = 2). Ligand L_1 has also been used to form a gallium hydride derivative $[Ga(L_1)H]$ (8), but indium analogues could not be made. β -ketoimine ligands,

 $\left[Me_2N(CH_2)\right]$ $\mathcal{N}(H)C(R')$ -CHC $(R')=O$ $\left[L_3H, R'=Me_3L_4H, R'=Ph \right)$, with a donor-functionalized Lewis base have also been synthesized and used to form gallium and indium alkyl complexes, $[Ga(L_3)Me_2]$ (9) and $[\text{In}(L_3)Me_2]$ (10), which were isolated as oils. The related gallium hydride complexes, $[G(a(L_n)H_2]$ (11, $n = 3$; 12, $n = 4$), were also prepared, but again no indium hydride species could be made. The complexes were characterized mainly by NMR spectroscopy, mass spectrometry, and single crystal X-ray diffraction. The β-ketoiminate gallium hydride compounds (8 and 11) have been used as single-source precursors for the deposition of Ga_2O_3 by aerosol-assisted (AA) CVD with toluene as the solvent. The quality of the films varied according to the precursor used, with the complex $[Ga(L_1)H]$ (8) giving by far the best quality films. Although the films were amorphous as deposited, they could be annealed at 1000 °C to form crystalline Ga_2O_3 . The films were analyzed by powder XRD, SEM, and EDX.

■ INTRODUCTION

Thin films of gallium oxide, $Ga₂O₃$, can be used as gas sensors for both reducing gases (e.g., CO, EtOH) 1,2 and oxidizing gases $(O_2)^{3,4}$ depending on the sensor temperature. They have been deposited using a variety of methods, [e.g.](#page-9-0), sputtering, 3 spray pyro[lys](#page-9-0)is, 5 and chemical vapor deposition (CVD). Recently, a significant amount of attention has focused on singl[e-s](#page-9-0)ource CVD m[et](#page-9-0)hods where a single molecular precursor, which contains at least one direct Ga–O bond, is used.⁶ The most common type of single-source precursor is gallium alkoxides:⁷ these compounds have been synthesized in a vari[e](#page-9-0)ty of ways, but t[h](#page-9-0)e most well-used methods are the reaction of $GaCl₃$ with an alkali metal alkoxide, 8 the reaction of trialkylgallium compounds with an alcohol, 9 the reaction of stabilized gallium hydrides with an alcohol, 10 and the reaction of gallium amide compounds with an alcohol. $11,12$ $11,12$ The final method is the most versatile, affording mono[-, b](#page-9-0)is-, or tris-alkoxide compounds of gallium.¹³ A comprehensive [revie](#page-9-0)w of single-source precursors to gallium and indium oxide has recently been published.¹⁴

Hom[ole](#page-9-0)ptic β -diketonate complexes of gallium have also been used as precursors, with some, e.g., $[Ga(acc)_{3}]$ (a[cac](#page-9-0) = acetylacetonate), being commercially available.^{15−17} However, these precursors are relatively involatile; therefore, high temperatures are needed to volatilize the [p](#page-9-0)r[ec](#page-9-0)ursor. To overcome this drawback, we attempted the synthesis of bis $(\beta$ diketonate) complexes of gallium and indium with a small third ligand, e.g., hydride. Unfortunately, we found that the high thermodynamic stability of the homoleptic tris(β -diketonate)

complexes prevented the isolation of gallium and indium bis(β diketonate) complexes.¹⁸

The hydrides of heavy group 13 metals (Ga, In, Tl) are an under-researched area [of](#page-9-0) chemistry, with the main issue being the thermal instability of most of the compounds. However, gallium hydride complexes are low mass and have a clean decomposition pathway; hence a hydride would be an ideal "coligand" for a molecular precursor. The binary hydrides $MH₃$ (M = Ga, In, Tl) all decompose well below room temperature, with strong Lewis bases needed to stabilize adducts of $\mathrm{Gal}_{3'}{}^{19}$ although a couple of gallium alkoxide hydride complexes have been reported starting from $[GaH_3(NMe_3)]$. The only roo[m](#page-9-0)temperature stable adducts of $InH₃$ have been reported by Jones, comprising bulky trialkylphosphine and NHC (Nheterocyclic carbene) adducts.²⁰ No TlH₃ complexes are known. A convenient entry point for gallium hydride chemistry is the adduct $[GaH_3(NMe_3)]$, [wh](#page-9-0)ich has limited stability at room temperature.²¹

As described above, precursors to thin films of gallium oxide have evolved from [co](#page-9-0)mmercially available compounds, such as $[Ga(acac)₃]$, to carefully designed molecules that take into account the requirements of the deposition technique.¹⁴ CVD often requires the precursor to be volatile, although solutionbased techniques offer an alternative method of get[tin](#page-9-0)g the precursor into the gas phase, and here solubility is the key

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Scheme 1. Synthesis of Bis(β -ketoimine) Ligands L₁H₂ and L₂H₂ and Bis(β -ketoiminate) Metal Complexes 1−8^a

 a Conditions: [a] solvent free, 150 °C; [b] 2.1 NaH, thf; [c] MCl3 (M = Al, Ga, In), hexane; [d] LiH/NaH/NaBH₄/LiAlH₄/NaBEt3H, thf, −78 °C $- RT$; [e] $[MH_3(NMe_3)] (M = Ga, In), Et_2O, -78 °C - RT$.

criterion. The β -ketoiminate ligand offers a potential means to address the aforementioned issues since the ability to functionalize the imino residue of the ligand means that the thermal stability (and solubility) of the precursor can be increased by tuning the groups attached to the nitrogen atom. Furthermore, it should be possible to isolate monomeric complexes and hence complexes with a high vapor pressure, particularly if hydride is used as the "coligand". Another advantage of employing this ligand type is the potential to enhance the surface reaction between the metal β -ketoiminates and the surface of a substrate. However, there have been very few previous reports on the reactivity of β-ketoiminate ligands with heavy group 13 metals and none specifically investigating the tuning of the ligand for CVD applications.

Dimethyl-gallium and -indium N-aryl-substituted β -ketoiminates have been reported, although the presence of an aryl group could lead to carbon contamination of the resulting films.²² Reaction of a lithiated β -ketoiminate with GaCl₃ surprisingly resulted only in a β -ketoimine adduct of GaCl₃, rathe[r t](#page-9-0)han the expected β -ketoiminate complex.²³ A donorfunctionalized lithium β -ketoiminate complex was reacted with InMe₃, affording the dimethylindium β -ketoimin[ate](#page-9-0) species,²⁴ and the crystal structure of complex 4 (Scheme 1) was previously reported by Vohs et $al.^{25}$ albeit no oth[er](#page-9-0) characterization data were given. However, none of these compounds have been used as precursors [for](#page-9-0) the CVD of group 13 oxide thin films, nor to stabilize gallium hydrides. Given that current precursors still suffer from chemical instability, poor reproducibility in the growth process, and less than favorable vapor pressures, an investigation into the use of group 13 $β$ ketoiminate complexes as single-source precursors was important given the advantages of the ligand outlined above. In this paper, we report the synthesis of new β -ketoimine ligands (and their sodium salts); their reactivity toward group 13 chloride, alkyl, and hydride compounds; and the viability of the new hydride complexes as precursors to thin films of gallium oxide.

■ RESULTS AND DISCUSSION

Compound Synthesis: Bis(β-ketoiminates). Ligand L_1H_2 was synthesized according to the literature procedure and was isolated as a beige crystalline solid.²⁶ Ligand L_2H_2 was synthesized in a similar manner, using 1,3-diaminopropane instead of 1,2-diaminoethane. 27 By reacti[ng](#page-9-0) a thf solution of L_1H_2 or L_2H_2 with a slight excess of NaH, the disodium salts 1 and 2 were formed (see the [Su](#page-9-0)pporting Information). These were isolated as white solids in good yield by removing solvents. However, it was also [possible to form complex](#page-9-0)es 1 and 2 in situ before adding the required metal chloride.

A hexane suspension of salt 1 was reacted with $AICI₃$ in a 1:1 ratio, forming complex $[A(L_1)Cl]$ (3) with concomitant elimination of NaCl. Similarly, complex 4 was synthesized by reacting an *in situ-generated* thf solution of 1 with GaCl₃. Compounds 3 and 4 were isolated in reasonable yields as yellow solids with elemental analyses of the solids consistent with the $[M(L_1)Cl]$ formulation. The 1H NMR spectra of the complexes were similar, showing a backbone CH resonance at ca. 5 ppm, ethylene bridge resonances at ca. 3.5 ppm, and methyl group peaks around 1.5−2.0 ppm. Complex 3 was crystallized by cooling a toluene solution to −18 °C, but the crystals were of poor quality and were unsuitable for single crystal X-ray diffraction. The solid state structure of complex 4 was previously reported by Vohs et al.²⁵ The proton resonances of the ethylene bridge in both 3 and 4, while appearing as a broad singlet in the ${}^{\bar{1}}H$ NMR spectr[um](#page-9-0) of ${\color{MyBlue}\textrm{L}_1\color{black}H_2}$, were seen as separate resonances in the metal complexes, showing an inequivalence of the two proton environments as a result of coordination to the metal center compared to the equivalent environments for the uncomplexed, freely rotating β -ketoimine. The observation of broad singlets in the case of 3 and multiplets in the case of 4 corresponding to the ethylene bridge protons suggests that the molecules possess a degree of fluxionality in solution.

Compound 5, an indium analogue, was synthesized using the hexane suspension method used for compound 3. This was crystallized by layering a concentrated CH_2Cl_2 solution with hexane, affording yellow needles, which were suitable for single crystal X-ray diffraction (Figure 1a, Table 1).

Figure 1. (a) ORTEP diagram showing complex 5a bridged by one equivalent of ligand L_1H_2 . Thermal ellipsoids are drawn at 50% probability, hydrogen atoms (bar H1) omitted for clarity. Hydrogen bonds are denoted by dashed lines, and atoms marked "i" are at the equivalent position (−x, $1 - y$, $-z$). (b) ORTEP diagram of compound 5. Thermal ellipsoids at 50% probability, hydrogen atoms omitted for clarity. Atoms marked "i" are at the equivalent position $(-x, -y - 1, -z - 1)$.

Table 1. Selected Bond Lengths for Compounds 5, 5a, 5·thf, 6, and 7

a
Bridging In−O bond length. ^bBond lengths for the neutral ligand. ^cBond length to thf. ^dMolecule 1 (trigonal bipyramidal geometry). ^eMolecule 2 (square-based pyramidal geometry).

The solid state structure showed that ligand L_1 had bonded to indium in the expected manner through both oxygens and both nitrogens, with a chloride ligand also bound to indium. However, instead of the anticipated five-coordinate In complex, a six-coordinate octahedral species (5a) was isolated with one equivalent of ligand L_1H_2 bridging between two In centers through the ketone oxygens. The complex is slightly distorted away from ideal octahedral geometry [trans bond angles between 159.68(6)−168.40(3) $^{\circ}$] as a result of the relatively large and electronegative chloride group, as well as the short ethylene backbone on L_1 . The anionic In-O bond lengthswhile slightly different—are significantly shorter than the In-O bond length to the bridging L_1H_2 molecule (Table 1). This is also reflected in the C−O bond lengths, with the delocalized bonding to the indium centers involving $O(1)$ and $O(2)$ resulting in C−O bond lengths that are significantly longer than typical C=O distances. The third oxygen, $O(3)$, being solely a two-electron donor to the indium center, is involved in a much shorter C−O bond length, which is consistent with a typical carbonyl. The proton attached to the amine nitrogen of the neutral ligand is involved in hydrogen bonding both with $O(3)$

on the same ligand and also with the adjacent $O(1)$ of the dianionic ligand. The ¹H NMR spectrum is consistent with the presence of two different ligand environments. One set of resonances (including an NH peak at 10.98 ppm) is very close to that of the free ligand; the other set corresponds to the dianionic ligand attached to 5a. The ratio of the two sets of peaks is 1:2, as expected.

The extra equivalent of L_1H_2 probably came from the incomplete reaction of L_1H_2 with NaH prior to the in situ addition of InCl₃. In order to prevent the formation of the bridged species, an isolated sample of salt 1 was reacted with InCl₃. This afforded a yellow solid in 45% yield, and the ${}^{1}H$ NMR spectrum showed only one set of ligand resonances. Crystallization from layering a concentrated CH_2Cl_2 solution of 5 with hexane afforded yellow crystals of compound 5 (Figure 1b, Table 1).

Although the solid state structure confirmed that there was no extra ligand bridging between two metal centers, compound 5 does exist as an oxygen-bridged dimer. The ketoiminate ligand was bound to indium in the expected manner with one chloride trans to the bridging oxygen comprising the

Figure 2. (a) ORTEP diagram of compound 6 and (b) ORTEP diagram showing one of two symmetry-independent molecules (with the severely distorted trigonal bipyramidal geometry) in the asymmetric unit of complex 7, see Figure S1 (Supporting Information) for the second molecule. Thermal ellipsoids at 50% probability, hydrogen atoms omitted for clarity.

coordination sphere. This was an unexpected result and is probably due to the inflexibility of the 2-carbon bridge in ligand $L₁$. By restricting the ligand from occupying a sufficient amount of the coordination sphere at indium, it enables a sixth donor group to coordinate to the vacant site, and in the absence of a suitable external Lewis base, dimerization occurs. This is evidenced from the trans angles around the indium center which involve L_1 : at 155.94(6)° and 164.06(7)°, they are a long way from the ideal 180°.

The In−O bond lengths (Table 1) confirm that the dative bridging In−O bond length is significantly longer than both the anionic In−O bond lengths. Unsur[pr](#page-2-0)isingly, there is a marked difference in length of the anionic In−O bonds owing to O(2) being involved in bridging. However, this difference may not be solely a result of $O(2)$ being involved in bridging because the In−N bond lengths are also significantly different from each other. The C−O bonds of L1 are also different from each other (as are the C−N bonds): this is different from other βketoiminate complexes reported in this paper, but not surprising owing to the differences noted for the In−O and In−N bond lengths. The ¹ H NMR spectrum of 5 was similar to those found for monomeric aluminum and gallium species 3 and 4 such that the inability of the ligand molecule to rotate freely results in an inequivalence of the two proton environments of the ethylene bridge.

The disodium salt 2 was similarly reacted with both $GaCl₃$ and InCl₃, forming complexes 6 [Ga(L₂)Cl] and 7 [In(L₂)Cl] (Scheme 1). Both complexes were isolated as yellow solids and were crystallized by layering concentrated CH_2Cl_2 solutions with hex[an](#page-1-0)e. The ${}^{1}H$ NMR spectra indicated that L_2 was binding to the metals in the expected manner with no NH proton observed: this was confirmed by structural characterization of both 6 and 7 (Figure 2, Table 1).

Compound 6 crystallized as a five-coordinate slightly distorted trigonal bipyramidal species i[n](#page-2-0) the triclinic space group \overline{PI} , with L_2 occupying four coordination sites and a chloride completing the coordination sphere. As expected, the largest ligand (chloride) occupies one of the equatorial sites. The degree of distortion away from ideal trigonal bipyramidal can be measured by calculating the τ value, which shows how far a five-coordinate complex is from ideal square-based pyramidal ($\tau = 0$) or trigonal bipyramidal ($\tau = 1$).²⁸ For compound 6, the τ value of 0.82 indicates that the degree of distortion away from ideal trigonal bipyramidal is sma[ll.](#page-9-0) This

can be seen from [the](#page-9-0) [largest](#page-9-0) [bond](#page-9-0) [angl](#page-9-0)e at gallium: the $O(1)$ − Ga(1)−N(2) angle of 172.66(5)° is not far from the ideal 180°.

There is a significant difference in bond lengths between the equatorial and axial groups. The equatorial Ga−O length [1.875(1) Å] is much shorter than the axial Ga−O bond length [1.976(1) Å], and a similar effect is observed with the Ga–N bond lengths, albeit the difference of 0.04 Å is not as marked as the case for the Ga−O bonds (0.1 Å). However, this difference is not manifested in the C−O bond lengths, which are identical within experimental error. They are also identical to the delocalized C−O bond lengths in compound 5a, despite the smaller ionic radius of Ga^{3+} compared to In^{3+} . However, there is a very small difference between the C−N bonds, and the longer of the two bonds is also slightly longer than the delocalized C−N bonds in complex 5a.

Compound 7 also crystallized as a five-coordinate species in the triclinic space group \overline{PI} with L_2 again occupying four of the coordination sites with a chloride ligand occupying the fifth. Although the molecular structure is extremely similar to that of compound 6, with the only difference being the slightly larger In(III) cation in place of $Ga(III)$, there is a significant difference in the manner in which compound 7 crystallizes, with two symmetry-independent molecules in the asymmetric unit. This results in an overall Z value of 4 as opposed to 2 in compound 6. The two independent molecules occupy vastly different geometries, with the molecule centered around $In(1)$ existing in a severely distorted trigonal bipyramidal geometry (τ = 0.70; Figure 2), whereas the molecule centered around In(2) adopts an almost ideal square-based pyramidal geometry ($\tau = 0.03$; Figure S1, Supporting Information). The origin for this is not clear, but the fact that compound 6 does not exhibit a similar distortion [may indicate a more sig](#page-9-0)nificant reason than simply crystal packing effects.

The In−O bond lengths across both molecules are in a range between $2.075(2)$ and $2.122(2)$ Å, but each molecule contains one "longer" In−O bond and one "shorter" In−O bond, with the difference between the two being statistically significant for each molecule. The same is true of the In−N bond lengths with the "longer" and "shorter" In−N bonds for each molecule being significantly different. However, the C−O bonds for each molecule are not different within experimental error, and the same is true for the In−N bonds (Table 1).

The $^1\mathrm{H}$ and $^{13}\mathrm{C}$ NMR spectra for 6 and 7 both supported the formation of the desired monomeric c[om](#page-2-0)plexes. Similarly to

that seen for 3, 4, and 5, a separation of the two $NCH₂$ resonances of the propylene bridge was observed in both cases as a result of coordination to the gallium (6) and indium (7) centers, showing an inequivalence of the proton environments. The broad resonances seen again suggest fluxional behavior of the molecules in solution.

Compounds 4 and 5 were both reacted with a variety of hydride sources (LiH, NaH, NaBH₄, LiAlH₄, NaBEt₃H) in an attempt to replace the chloride ligand with hydride. However, in all cases, no reaction was observed, and the ¹H NMR spectrum merely indicated that starting material remained. In order to try to remove the chloride ligand completely, a THF solution of compound 5 was reacted with one equivalent of freshly formed C_8K . Although no color change was observed, slow diffusion of hexane into the THF solution of the reaction product yielded yellow crystals, which were suitable for single crystal X-ray analysis (Figure 3, Table 1).

Figure 3. ORTEP diagram of compound 5·thf. Thermal ellipsoids at 50% probability, hydrogen atoms omitted for clarity.

Compound 5·thf crystallized as an octahedral species with one equivalent of L_1 , one chloride ligand, and one thf molecule comprising the coordination sphere. The chloride and thf ligands are mutually trans with the four ligand donor atoms to the metal existing in a single plane [RMS deviation for $O(1)$, $O(2)$, N(1), N(2) = 0.0455 Å]. The metal atom is out of this plane by $0.277(1)$ Å. The In–O bond lengths involving the ligand are identical within experimental error, as are the In−N bonds, although there is a marked difference between the In−O

bonds from the ligand and the In−O bond of the thf ligand. They are also very similar to the In−O and In−N bonds found in complexes 5a and 7. This is also borne out by the C−O and C−N bonds, which are identical within experimental error.

Although it is surprising that compound 5 did not react with C_8K , it is probable that carrying out the reaction in thf caused complex 5·thf, which is kinetically inert, to form prior to the reaction with C_8K . However, switching the solvent to Et_2O and repeating the reaction of 5 with C_8K also did not lead to any reaction taking place.

Owing to the unreactivity of compound 4, in order to prepare a gallium hydride derivative of ligand L_1H_2 , it was reacted directly with a freshly prepared ethereal solution of $[GaH_3(NMe_3)]$ (Scheme 1). A pale yellow solution with a white suspension formed, and the solid was removed by filtration. Compound 8 wa[s i](#page-1-0)solated as a yellow powder in 71% yield by removal of the volatiles, and the ¹H NMR spectrum showed no resonance associated with the NH proton, in addition to a small peak at 5.56 ppm characteristic of gallium hydrides. All attempts at crystallizing compound 8 only resulted in the formation of a microcrystalline solid unsuitable for single crystal X-ray diffraction, but elemental analysis was consistent with the formation of compound 8.

In an attempt to synthesize an indium analogue of compound 8, ligand L_1H_2 was reacted with a freshly prepared ethereal solution of $\text{[InH}_{3}(NMe_{3})\text{]}$ (Scheme 1). At -78 °C, no reaction was observed, but upon slow warming to RT, a gray precipitate of indium metal formed in a pal[e](#page-1-0) brown solution. After filtration and removal of the solvents, ¹H NMR spectroscopic analysis found that the brown solution only contained ligand L_1H_2 . While complexes of the type $\left[\text{InH}(L)_2 \right]$ $(L =$ formamidinate) have been previously isolated,²⁹ in our case, it is unknown whether any reaction between L_1H_2 and $\text{[InH}_{3}(NMe_{3})\text{]}$ took place: given the kinetic an[d t](#page-9-0)hermal sensitivity of indium hydride complexes, it is possible that the indium hydride starting material decomposed before any reaction took place. The use of isolated $\text{[InH}_{3}(\text{NHC})\text{]}^{30}$ as a starting material did not lead to the formation of $[InH(L_1)],$ with no reaction observed to take place.

Compound Synthesis: Donor-Functionalized β-Ketoiminates. Compounds such as $[Ga(O^iPr)_3]$ usually exist as oligomers, but by using donor-functionalized alkoxides (which have a Lewis base attached to the alkoxide moiety), it is possible to isolate monomeric and dimeric alkoxides.^{31,32} Through a judicious choice of the primary amine, it should

^aConditions: [a] solvent free, 150°; [b] MMe₃ (M = Ga, In), toluene, 110 °C, 16 h; [c] [GaH₃(NMe₃)], Et₂O, −78 °C − RT.

be possible to form a β -ketoimine ligand with an extra Lewis base, i.e., donor-functionalized β -ketoiminates. The presence of the extra Lewis base should lead to coordinative saturation of the metal center, enabling isolation of additional hydride species. Hence, L_3H (R = Me) was synthesized by combining acetylacetone with N,N-dimethylpropylenediamine, then heating the mixture to 150 °C for four hours (Scheme 2). After cooling and extraction into diethyl ether, drying over anhydrous $Na₂SO₄$ removed sufficient residual water such that [n](#page-4-0)o $H₂O$ signal was observed in the ¹H NMR spectrum of the crude product. Indeed, the crude product (an orange oil) was of sufficient purity for further reactivity studies. Ligand L_4H (R = Ph) was synthesized in a similar manner, starting from dibenzoylmethane instead of acetylacetone. The product was isolated as an extremely viscous orange-brown oil, again with no purification step necessary as judged from the ¹H NMR spectrum. In both cases, the NH peak was observed at a very downfield position of 10.75 ppm (L_3H) and 11.87 ppm (L_4H) . Coupling of the NH proton to the $CH₂$ group was also observed, with the signal corresponding to the latter group appearing as a doublet of triplets at 3.20 (L_3H) and 2.99 (L_4H) ppm.

In an attempt to gauge the reactivity of ligand L_3H , it was reacted with one equivalent of GaMe₃ in Et₂O at -78 °C. After warming to RT and stirring for 16 h, removal of all volatiles afforded a gelatinous pale brown oil. ¹H NMR spectroscopy of the oil revealed a reaction had taken place, but two products (in a 1:1 ratio) were present. By analyzing the integrals of the peaks in the Ga−Me region of the spectrum (ca. 0.0 ppm) relative to that for the CH peak on the backbone (ca. 5.0 ppm), in addition to the peak corresponding to the $CH₂$ group next to the amine NH (or N[−]), it was determined that the two products were (i) a simple adduct of L_3H with $GaMe_3$ (probably through the lone pair of the $NMe₂$ group) and (ii) compound 9 (Scheme 2). Dissolving the oil in thf and refluxing for 4 h resulted in increased conversion to compound 9 of 68%, but a prolonged reflux [in](#page-4-0) toluene (16 h) was required in order for complete conversion to compound 9 to occur. This indicated that ligand L_3H was not very reactive, with long reaction times at high temperatures needed for complete conversion to occur. Reaction of L_3H with InMe₃ followed similar lines, with prolonged reflux at high temperatures needed for full conversion to complex 10: further evidence that L_3H does not react quickly with the reactive $MMe₃$ (M = Ga, In).

Compound ⁹ was isolated as a gelatinous brown oil with the ¹ ¹H NMR spectrum exhibiting the expected differences from that of L3H, namely, no NH proton in the 11−12 ppm range and a triplet (rather than a doublet of triplets) for the methylene group next to the amide nitrogen. A singlet at 0.02 ppm corresponding to the Ga−Me groups was characteristic of Ga−Me protons. Similarly, compound 10 was also isolated as a gelatinous brown oil with the chemical shifts in the ${}^{1}H$ and ${}^{13}C[{^{1}H}]$ NMR spectra occurring at very similar values. ${}^{13}C{^1H}$ NMR spectra occurring at very similar values.

After discovering that ligand L_3H did react, albeit slowly, in the expected manner with $GaMe₃$, a freshly prepared solution of $[GaH_3(NMe_3)]$ in Et₂O was added to an ethereal solution of $L₃H$ (Scheme 2). A small amount of gas was given off, and a color change to pale yellow-green was observed, along with the formation of a [w](#page-4-0)hite solid. After removing the $Et₂O$, extracting the solid into hexane afforded a yellow-green oil in 35% yield, which had a broad peak at 5.50 ppm in the ¹H NMR spectrum, characteristic of gallium hydrides. The ¹H NMR spectrum of compound 11 contained the expected peaks for the ligand coordinated to a metal, notably a lack of amine NH and a triplet for the methylene group next to the amide N[−]. However, it proved impossible to crystallize compound 11; thus it was not possible to confirm the solid state structure, although a fivecoordinate species with three coordination sites occupied by $L₃$ and two hydrides is likely observed on the basis of mass spectrometric and NMR spectroscopic data.

In an attempt to improve on the low yield of compound 11, an alternative synthesis was employed. By forming the hydrochloride salt of ligand L3H, it was possible to react L_3H ·HCl directly with $LiGaH_4$ instead of going through the intermediate $[GaH_3(NMe_3)]$. A white solid in a green solution was again produced, and after removing the $Et₂O$ and extracting the residue into hexane, a viscous green-yellow oil was isolated in an improved 61% yield. Upon standing overnight at RT, colorless crystals formed which were suitable for X-ray diffraction analysis. Unfortunately, the crystals turned out to be the unreacted hydrochloride salt L_3H **·HCl** (Figure S2, Supporting Information).

In an attempt to form a crystalline gallium hydride complex [analogous to compound](#page-9-0) 11, it was thought that adding steric bulk to the ligand backbone would result in a solid product. Thus, an ethereal solution of ligand $L₄H$ was reacted with a freshly prepared solution of $[GaH_3(NMe_3)]$ in Et₂O (Scheme 2). The reaction proceeded as expected, and compound 12 was isolated in 54% yield as a yellow-green oil. Although compound [1](#page-4-0)2 was significantly more viscous than compound 11 (consistent with the higher viscosity of L4H compared to $L₃H$), it was still oily and could not be crystallized. Nonetheless, strong indications that compound 12 had been made were found in the ¹H NMR spectrum where signals characteristic of the coordinated β -ketoiminate were observed, namely, no NH signal at 11.9 ppm and a triplet at 3.22 ppm for the methylene group next to the amide nitrogen.

The Ga/O ratio in complexes 11 and 12 is only 1:1, but for $Ga₂O₃$ the ratio is 1:1.5. In order to synthesize a precursor, which would not afford oxygen-deficient films, attempts were made to react a second equivalent of L_3H with complex 11. However, when one equivalent of $L₃H$ was added to a toluene solution of 11, no reaction occurred. Adding excess $L₃H$ had no effect, and refluxing the reaction merely led to decomposition of 11, with the formation of metallic gallium. Similar results were obtained with ligand L_4 and complex 12. Although the formation of oxygen-deficient films is undesirable, postdeposition annealing of films in the air is known to afford stoichiometric Ga_2O_3 .³³

Unfortunately, due to compounds 9−12 all being oils, elemental analysis co[uld](#page-10-0) not be carried out under anaerobic conditions. Attempting elemental analysis rapidly under aerobic conditions only resulted in decomposition. However, the purity of these complexes has been confirmed via ${}^{1}H$ and ${}^{13}C(^{1}H)$ NMR spectroscopy and also mass spectrometry, where the molecular ion was observed for all compounds.

With gallium β -ketoiminate hydride complexes 11 and 12 in hand, attention turned to the synthesis of indium hydride analogues. Ligand L_3H was reacted with a freshly prepared ethereal solution of $\text{[InH}_3(NMe_3)$] at −78 °C, but upon warming to RT a gray precipitate of indium metal formed: ¹H NMR spectroscopic analysis of the solution only revealed the presence of L_3H . A similar result was obtained when L_4H was used. Further investigations into the reaction between [InH₃(NMe₃)] and β -ketoimine ligands revealed that the onset of formation of In metal in each case was ca. −30 °C, a

Figure 4. XRD pattern of the film deposited on quartz by AACVD of compound 8 after annealing at 1000 °C for 12 h, consistent with crystalline $Ga₂O₃$ (solid bars).

similar temperature to the known decomposition temperature of $\left[\text{InH}_{3}(N\text{Me}_{3})\right]^{34}$ This could possibly indicate that the β ketoimine ligands are insufficiently reactive at low temperatures (−78 °C), and [t](#page-10-0)he indium hydride starting material decomposes before any reaction with the ligand can take place.

Chemical Vapor Deposition. Anticipating that the use of hydride ligands would enhance the volatility of galliumcontaining precursors, compounds 8 and 11 were used as precursors to thin films of $Ga₂O₃$. Initial studies were carried out using a simple low pressure (LP)CVD tube furnace, but it was found that the compounds decomposed before any significant sublimation occurred and no films were obtained. In order to get the precursors into the reactor, attention turned to using aerosol-assisted (AA)CVD instead. This setup uses a solution of the precursor (usually in toluene) which is nebulized and carried into the reactor chamber using a stream of N_2 , whereby the solvent evaporates leaving the precursor to decompose onto the substrate.

The best deposition conditions were found to be 1 L min⁻¹ of N_2 carrier gas and a substrate temperature of 450 °C. The films grown using compound 11 as a precursor were patchy and poorly adherent to the substrate, with a large amount of white powdery deposit observed. Powder X-ray diffraction (XRD) showed the films to be amorphous, as is expected from gallium oxide grown at low temperatures. Energy dispersive X-ray (EDX) analysis of the film showed that gallium was present, but the film was too thin to calculate the Ga/O ratio because breakthrough to the underlying glass substrate took place. Altering the deposition conditions did not result in the formation of better-quality films; hence, compound 11 was abandoned as an unsuitable precursor.

Films grown from compound 8 proved to be of much better quality. The coverage of the substrate was much improved with a transparent, adherent film deposited on the bottom plate, and a small amount of white powdery material also deposited onto the top plate, which is the glass plate that rests 8 mm above the surface of the substrate. Deposition on the substrate and top plate is due to the thermophoretic force that gas-phase particles are subjected to during AACVD. Since the flow of gas in the reactor is laminar rather than turbulent, thermophoresis is usually the dominant force in determining the deposition location of particles; hence, deposition also occurs on the elevated surfaces above the actual surface that requires coating. The top plate was measured to be ∼50−70 °C lower in

temperature than the bottom plate. Films deposited on the substrate were used in the analysis below.

Powder XRD analysis of the as-deposited transparent film revealed that the material was amorphous, but depositing on quartz and annealing in the air at 1000 °C for 12 h resulted in the formation of a crystalline film of $Ga₂O₃$ (Figure 4). EDX analysis of the as-deposited film again showed breakthrough to the glass substrate making calculation of an accurate Ga/O ratio difficult, although the presence of gallium in the films was confirmed. SEM images showed that the as-deposited film was composed of aggregated spherical globules (Figure 5), but after annealing, the film composition became much smoother and more uniform, with few globular surface features.

Figure 5. SEM images of the film obtained by AACVD of a toluene solution of 8 on (a) glass and (b) quartz. The quartz film was annealed at 1000 °C for 4 h.

The optical properties of the films deposited from 8 were studied by UV/visible spectroscopy between 90 and 1100 nm. Conducting a Tauc plot of the UV/visible data indicated that the band gap of the films deposited from 8 were ∼4.65 eV, which provides further support for the formation of $Ga₂O₃$ since the band gap of gallium oxide is ∼4.2−4.7 eV. Transmission and reflectance measurements between 200 and 2550 nm showed that the films displayed minimal reflectivity (5−10%) and were highly transparent, as shown in Figure 6 with transparency ranges from 80% to 90% in the visible. Previous deposition of $Ga₂O₃$ via AACVD of dialkylalko[x](#page-7-0)ogallanes of the type $[R_2Ga(OR')]_2$ $(R = Me, Et; R' =$ $CH_2CH_2NMe_2$, CH_2CH_2OMe , etc.) typically resulted in the deposition of gray or brown films indicative of carbon contamination, probably due to the retention of carbon from the Ga−C bond.32,33,35 In contrast, compound 8 afforded transparent films (as deposited), suggesting minimal carbon contamination. I[ndeed,](#page-10-0) no carbon was detected via EDX

Figure 6. Vis/IR transmission spectra of a film obtained by AACVD of a toluene solution of 8.

analysis, so carbon contamination levels as a direct result of the precursors used are low (<5 at.%), which could be attributed to the presence of the hydride ligand in 8 resulting in minimal contamination.

■ CONCLUSIONS

In conclusion, we have demonstrated that it is possible to synthesize a wide range of $β$ -ketoimine ligands and attach them to group 13 metals. The synthesis of gallium β -ketoiminate hydrides can be accomplished by reacting the free ligand directly with $[GaH_3(NMe_3)]$, but analogous indium complexes cannot be made, with indium β-ketoiminate chloride complexes proving to be unreactive toward hydride sources (as well as even more reactive species such as C_8K). Gallium hydride complexes 8 and 11 have been used as precursors to thin films of gallium oxide. Compound 8 proved the superior precursor, affording transparent, adherent films. Extension of the β ketoiminate chemistry to other main group metals is currently in progress.

EXPERIMENTAL SECTION

All reactions involving metal complexes were carried out under nitrogen using standard Schlenk and glovebox techniques. AlCl₃ was obtained from Acros Organics. GaCl₃ (10 mesh beads, 99.99%), LiH, and amines were bought from Sigma Aldrich, β -diketones and InCl₃ from Alfa Aesar: all were used without further purification. $GaMe₃$ and InMe₃ were supplied by SAFC Hitech Ltd. $\left[\text{GaH}_{3}\text{(NMg}_{3})\right]^{21}$ and $\left[\text{InH}_{3}(\text{NMe}_{3})\right]$ ³⁴ along with ligands L_{1}H_{2} and L_{2}H_{2} ^{26,27} were synthesized according to literature procedures. Details of the [li](#page-9-0)gand syntheses, sodi[um](#page-10-0) salt formation, and compounds 5a an[d](#page-9-0) [5](#page-9-0)·thf are contained in the Supporting Information.

H and ¹³C{¹H} NMR spectra were obtained on a Bruker AMX-400 spectrometer, operating at 295 K and 400.12 MHz (¹H). Signals are reported relative [to](#page-9-0) SiMe₄ (δ = 0.00 ppm), and the following abbreviations are used: s (singlet), d (doublet), t (triplet), m (multiplet), br (broad). Deuterated solvents were obtained from Goss Scientific and were dried and degassed over molecular sieves prior to use. Mass spectra were obtained using a Micromass 70-SE spectrometer using chemical ionization (CI) with methane reagent gas. The expected pattern for each $[M]^+$ reported was observed. Elemental analyses were obtained at UCL.

 $[AI(L₁)CI]$ (3). Compound 1 (540 mg, 2.0 mmol) was suspended in hexane (20 mL) and added slowly to a solution of AlCl_3 (270 mg, 2.0 mmol) in hexane (20 mL) at −78 °C. The reaction was stirred for 30 min, then warmed to RT and stirred for 16 h. After this time, solvents were removed, the solid extracted into toluene and filtered. The resulting yellow solution was cooled to −18 °C, affording 200 mg of a yellow crystalline material (35% yield).

 $\delta_{\rm H}$ (400.1 MHz, CDCl₃): 5.04 (2H, s, CH), 3.21 and 2.65 (each 2H, br s, CH₂), 1.99 (6H, s, COCH₃), 1.43 (6H, s, CNCH₃) ppm. δ_C (100.6 MHz, CDCl₃): 180.6 (CO), 173.6 (CN), 100.7 (CH),

45.8 (CH₂), 25.8 (CH₃, COCH₃), 22.4 (CH₃, CNCH₃) ppm.

Mass spec (m/z) : 284 $[M]^+$, 249 $[M - Cl]^+$.

Analysis Calcd. for C₁₂H₁₈N₂O₂AlCl: C, 50.62; H, 6.37; N, 9.84. Found: C, 50.71; H, 6.49; N, 9.28.

 $[Ga(L_1)Cl]$ (4). A suspension of compound 1 (2.68 g, 10.0 mmol) in thf (40 mL) was added to a solution of $GaCl₃$ (1.76 g, 10.0 mmol) in thf (20 mL) at −78 °C and stirred for 30 min. The reaction was warmed to RT then refluxed for 16 h. After this time, the reaction was cooled and filtered and the resulting NaCl extracted with thf. The filtrates were combined, and solvents were removed in vacuo. The resulting yellow solid was dissolved in minimal CH_2Cl_2 (ca. 10 mL) and precipitated out by the rapid addition of hexane, affording 2.29 g of complex 4 in 70% yield.

 $\delta_{\rm H}$ (400.1 MHz, CDCl₃): 5.26 (2H, s, CH), 3.62 and 3.51 (each 2H, m, CH₂), 2.08 (6H, s, COCH₃), 2.02 (6H, s, CNCH₃) ppm.

 δ_C (100.6 MHz, CDCl₃): 183.6 (CO), 173.3 (CN), 98.8 (CH), 45.1 (CH_2) , 26.7 (CH₃, COCH₃), 22.6 (CH₃, CNCH₃) ppm.

Mass spec (m/z) : 326 $[M]^+$, 291 $[M - Cl]^+$.

Analysis Calcd. for $C_{12}H_{18}N_2O_2$ GaCl: C, 44.01; H, 5.54; N, 8.55. Found: C, 44.00; H, 5.49; N, 8.26.

 $\left[\ln(L_1)$ Cl] (5). A suspension of compound 1 (2.68 g, 10.0 mmol) in hexane (40 mL) was added to a suspension of $InCl₃$ (2.21 g, 10.0 mmol) in hexane (20 mL) at −78 °C and stirred for 30 min. The reaction was warmed to RT, then refluxed for 16 h. After this time, the reaction was cooled and filtered and the resulting NaCl extracted with hexane. The filtrates were combined, and solvents were removed in vacuo. The resulting yellow solid was dissolved in minimal CH_2Cl_2 (ca. 10 mL) and crystallized through vapor diffusion of hexane into the CH_2Cl_2 solution, affording 1.67 g of complex 5 in 45% yield

 $\delta_{\rm H}$ (400.1 MHz, CDCl₃): 5.26 (2H, s, CH), 3.62 and 3.51 (each 2H, m, CH₂), 2.08 (6H, s, COCH₃), 2.02 (6H, s, CNCH₃) ppm.

 δ_C (100.6 MHz, CDCl₃): 183.6 (CO), 173.3 (CN), 98.8 (CH), 45.1 (CH₂), 26.7 (CH₃, COCH₃), 22.6 (CH₃, CNCH₃) ppm.

Mass spec (m/z) : 372 $[M]^+$, 337 $[M - Cl]^+$.

Analysis Calc. for $C_{12}H_{18}N_2O_2InCl$: C, 38.69; H, 4.87; N, 7.52. Found: C, 38.82; H, 5.01; N, 7.46.

 $[Ga(L₂)Cl]$ (6). A suspension of compound 2 (570 mg, 2.0 mmol) in hexane (30 mL) was cooled to −78 °C and added to a solution of GaCl3 (352 mg, 2.0 mmol) in hexane (20 mL) at −78 °C. The reaction was stirred for 15 min, warmed to RT, and then stirred for 16 h. After this time, the reaction was filtered, solvents removed, and the resulting yellow/brown solid dissolved in minimal CH_2Cl_2 (ca. 5 mL) and layered with hexane. Yellow crystals (270 mg) of the title compound formed in 38% yield.

 $\delta_{\rm H}$ (400.1 MHz, CDCl₃): 5.06 (2H, s, CH), 3.71 and 3.46 (each 2H, br s, NCH₂), 2.01 (6H, s, COCH₃), 2.00 (6H, s, CNCH₃), 1.87 (2H, quintet, $J = 6.5$ Hz, $CH₂$) ppm.

 δ_C (100.6 MHz, CDCl₃): 98.8 (CH), 47.2 (NCH₂), 30.3 (CH₂), 26.5 (CH₃, COCH₃), 18.8 (CH₃, CNCH₃), ppm. (CO) and (CN) not detected.

Analysis Calcd. for $C_{13}H_{20}N_2O_2$ GaCl: C, 45.75; H, 5.90; N, 8.20. Found: C, 45.44; H, 6.04; N, 8.28.

 $[In(L₂)Cl]$ (7). The procedure described for compound 6 was followed, with $InCl₃$ (442 mg, 2.0 mmol) used in place of GaCl₃. Yellow crystals (270 mg) of 7 were isolated in 35% yield.

 δ_H (400.1 MHz, CDCl₃): 4.94 (2H, s, CH), 3.76 and 3.47 (each 2H, br s, NCH₂), 2.63 (2H, br s, CH₂), 2.02 (6H, s, COCH₃), 1.99 $(6H, s, CNCH₃)$ ppm.

 δ_C (100.6 MHz, CDCl₃): 185.8 (CO), 176.0 (CN), 98.0 (CH), 51.9 (NCH₂), 29.1 (CH₂), 27.6 (CH₃, COCH₃), 23.2 (CH₃, CNCH₃) ppm.

Mass spec (m/z) : 386 [M]⁺, 351 [M – Cl]⁺, 238 [L₂H₂]⁺ .

Analysis Calcd. for C₁₃H₂₀N₂O₂InCl: C, 40.39; H, 5.21; N, 7.25. Found: C, 40.17; H, 5.30; N, 7.59.

[Ga(L₁)H] (8). A freshly prepared solution of $[GaH_3(NMe_3)]$ (5.0) mmol) in Et₂O (50 mL) was cooled to -78 °C and added to a suspension of L_1H_2 (1.12 g, 5.0 mmol) in Et₂O (20 mL) at −78 °C. The suspension was stirred for 15 min, then warmed to RT and stirred for 16 h. After this time, a yellow solution with a white suspension had formed. The reaction was filtered, and volatiles were removed in vacuo, affording 1.04 g of a yellow solid in 71% yield.

 δ_H (400.1 MHz, C_6D_6): 5.56 (1H, v br s, GaH), 4.80 (2H, s, CH), 2.80−2.89 and 2.58−2.68 (each 2H, m, CH₂), 1.90 (6H, s, COCH₃), 1.39 (6H, s, $CNCH_3$) ppm.

 δ_C (100.6 MHz, C₆D₆): 182.45 (CO), 171.25 (CN), 97.62 (CH), 45.28 (CH₂), 26.70 (CH₃, COCH₃), 21.52 (CH₃, CNCH₃) ppm.

Analysis Calcd. for C₁₂H₁₉N₂O₂Ga: C, 35.69; H, 6.99; N, 6.94. Found: C, 35.75; H, 6.91; N, 7.06.

 $[Ga(L_3)Me_2]$ (9). A solution of $GaMe_3$ (574 mg, 5.0 mmol) in toluene (30 mL) was cooled to −78 °C, and ligand $\dot{\text{L}}_3\text{H}$ (920 mg, 5.0 mmol) was added dropwise. The solution was gradually warmed to RT with the evolution of methane gas, then refluxed for 16 h. After this time, solvents were removed, affording 1.35 g of a gelatinous brown liquid in 95% yield.

 δ_H (400.1 MHz, C₆D₆): 4.67 (1H, s, CH), 3.13 (2H, t, J = 7.5 Hz, NCH₂), 1.94−1.99 (8H, m, Me₂NCH₂ + N(CH₃)₂), 1.85 (3H, s, COCH₃), 1.51 (3H, s, CNCH₃), 1.49 (2H, quintet, $J = 7.0$ Hz, CH₂), 0.02 (6H, s, $GaCH₃$) ppm.

 δ_C (100.6 MHz, C₆D₆): 180.43 (CO), 171.46 (CN), 97.96 (CH), 56.67 (NCH₂), 46.80 (Me₂NCH₂), 45.30 (N(CH₃)₂), 28.32 (CH₂), 26.35 (CH₃, COCH₃), 20.53 (CH₃, CNCH₃), −6.78 (CH₃, GaCH₃) ppm.

Mass spec (m/z) : 283 $[M]^{+}$. .

 $[In(L₃)\overline{Me}_{2}]$ (10). The procedure for compound 9 was followed with $ImMe₃$ (800 mg, 5.0 mmol) being used in place of $GaMe₃$. A total of 1.51 g of complex 10 was isolated as a gelatinous brown liquid in 92% yield.

 $\delta_{\rm H}$ (400.1 MHz, C₆D₆): 4.81 (1H, s, CH), 3.04 (2H, t, J = 6.0 Hz, NCH₂), 2.00 (3H, s, COCH₃), 1.93 (2H, t, $J = 6.0$ Hz, Me₂NCH₂), 1.76 [6H, s, N(CH₃)₂], 1.56 (3H, s, CNCH₃), 1.25 (2H, quintet, J = 6.0 Hz, $CH₂$), 0.00 (6H, s, InCH₃) ppm.

 δ_C (100.6 MHz, C₆D₆): 183.90 (CO), 171.67 (CN), 97.59 (CH), 58.38 (NCH₂), 49.15 (Me₂NCH₂), 45.38 [N(CH₃)₂], 28.06 (CH₃, COCH₃), 27.89 (CH₂), 21.03 (CH₃, CNCH₃), –6.78 (CH₃, InCH₃) ppm.

Mass spec (m/z) : 328 $[M]^{+}$. .

 $[Ga(L₃)H₂]$ (11). (Method 1) A freshly prepared solution of [GaH₃(NMe₃)] (5.0 mmol) in Et₂O (30 mL) was cooled to -78 °C, and ketoimine L_3H (920 mg, 5.0 mmol) was added dropwise. A white precipitate formed; the suspension was warmed to RT and stirred for 16 h. After this time, solvents were removed, the solid extracted with hexane $(2 \times 20 \text{ mL})$, and the hexane extracts concentrated, affording 446 mg of a yellow-green oil in 35% yield.

(Method 2) A freshly prepared solution of $LiGaH₄$ (5.0 mmol) in Et₂O (30 mL) at -78 °C was added to L₃H·HCl (1.10 g, 5.0 mmol). The reaction was stirred for 15 min, warmed to RT, and stirred for 16 h. After this time, solvents were removed and the solid extracted with hexane $(3 \times 20$ mL), and the hexane extracts were combined and concentrated, affording 777 mg of a yellow oil in 61% yield.

 $\delta_{\rm H}$ (400.1 MHz, C₆D₆): 5.50 (2H, v br s, GaH), 4.69 (1H, s, CH), 3.08 (2H, t, J = 7.0 Hz, NCH₂), 1.97 (2H, m, Me₂NCH₂), 1.94 [6H, s, N(CH₃)₂], 1.82 (3H, s, COCH₃), 1.46−1.49 (2H, m, CH₂), 1.45 (3H, s, $CNCH₃$) ppm.

 δ_C (100.6 MHz, C₆D₆): 181.14 (CO), 172.30 (CN), 98.40 (CH), 56.48 (NCH₂), 47.71 (Me₂NCH₂), 45.19 [N(CH₃)₂], 27.23 (CH₂), 26.20 (CH₃, COCH₃), 20.61 (CH₃, CNCH₃) ppm.

Mass spec (m/z) : 255 [M]⁺.

 $[Ga(L_4)H_2]$ (12). Procedure 1 for compound 11 was followed, using ketoimine L_4H (1.54 g, 5.0 mmol). A total of 1.03 g of complex 12 was isolated as a yellow-green oil in 54% yield.

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 $\delta_{\rm H}$ (400.1 MHz, C_6D_6): 7.87–7.91 (2H, m, Ar), 7.04–7.11 (6H, m, Ar), 6.97−7.01 (2H, m, Ar), 5.81 (1H, s, CH), 5.55 (2H, v br s, GaH), 3.22 (2H, t, J = 7.0 Hz, NCH₂), 2.00 (2H, t, J = 6.0 Hz, Me₂NCH₂), 1.92 [6H, s, N(CH₃)₂], 1.42 (2H, quintet, J = 6.5 Hz, CH₂) ppm.

 δ_C (100.6 MHz, C₆D₆): 177.31 (CO), 175.10 (CN), 139.53, 139.40 (C, Ar), 130.46, 128.98, 128.59, 128.34, 127.50, 127.27 (CH, Ar),

96.95 (CH), 57.51 (NCH₂), 51.32 (CH₂, Me₂NCH₂), 45.14 $[N(CH_3)_2]$, 28.49 (CH₂) ppm.

Mass spec (m/z) : 379 $[M]^{+}$. .

AACVD. For AACVD experiments, nitrogen (99.99%) was obtained from BOC and used as supplied. Depositions were obtained on SiCO barrier layer (50 nm) float-glass of dimensions ca. 90 mm × 45 mm \times 4 mm. Prior to use, the glass substrates were cleaned using petroleum ether (60–80 °C) and ^īPrOH, then dried in the air. The precursor (ca. 300 mg) was dissolved in toluene (ca. 30 mL) and vaporized at room temperature by use of a PIFCO ultrasonic humidifier. The aerosol was carried into the reactor using nitrogen through a brass baffle to obtain a laminar flow. A graphite block containing a Whatman cartridge heater was used to heat the glass substrate. The temperature of the substrate was monitored by a Pt−Rh thermocouple, and the horizontal bed reactor was heated to the required temperature before diverting the nitrogen line through the aerosol and hence to the reactor. The total time for the deposition process was ca. 2 h. The coated glass substrate was cut into ca. 1 cm × 1 cm squares for subsequent analysis by scanning electron microscopy (SEM).

Film Analysis Methods. X-ray powder diffraction patterns were measured on a Siemens D5000 diffractometer using monochromated Cu K α radiation ($\lambda = 1.5400$ Å). The diffractometer used glancing incident radiation (1.5°). The films on the glass substrates were indexed using Unit Cell and compared to database standards. SEM was carried out on a JEOL 6301 filament scanning electron microscope.

Crystallography. A summary of the crystal data, data collection, and refinement for crystallographically characterized compounds are given in Table 2. The data set for compound 5 was collected at 100(2) K on a Rigaku AFC12 goniometer equipped with an enhanced sensitivity (HG) Saturn724+ detector mounted at the window of an FR-E+ SuperB[rig](#page-8-0)ht Mo rotating anode generator with VHF Varimax optics (70 μ m focus). The program used for control and integration was CrystalClear.³⁷ Data sets for compounds 5a, 5^{\cdot thf, and L₃H \cdot HCl} were collected at 120(2) K on an Enraf-Nonius Kappa CCD area detector diffract[om](#page-10-0)eter with an FR591 rotating anode (Mo K α) radiation) in ω scanning mode with ψ and ω scans to fill the Ewald sphere. The programs used for control and integration were Collect, Scalepack, and Denzo.^{38,39} Data sets for compounds 6 and 7 were obtained on a Bruker SMART APEX CCD diffractometer using graphite-monochroma[ted](#page-10-0) Mo K α radiation at 150(2) K. Data reduction and integration were carried out with SAINT+ and absorption corrections applied using SADABS.⁴⁰

The crystals were mounted on mitogen loops (5, 5a, 5·thf, $L₃H·HCl$) or on a glass fiber with silicon greas[e \(](#page-10-0)6, 7) from Fomblin. All solutions and refinements were performed using the WinGX package and all software packages within.⁴¹ All non-hydrogen atoms were refined using anisotropic thermal parameters, and hydrogens were added using a riding model. Hydroge[ns](#page-10-0) bonded to nitrogen in 5a and L3H·HCl were located in the Fourier difference map and refined isotropically. The compound L_3H **·HCl** crystallized in the space group $P2₁$ as a racemic twin. The crystals were small and weakly diffracting, resulting in low C−C bond precision.

■ ASSOCIATED CONTENT

S Supporting Information

Experimental and spectroscopic details for the synthesis of ligands L_1H_2 , L_2H_2 , L_3H , and L_4H (and L_3H **·HCl**) and spectroscopic data for compounds 5a and 5·thf are included as supporting data, along with X-ray crystallographic data in CIF format for the structures of compounds 5, 5a, 5·thf, 6, 7, and L3H·HCl. This material is available free of charge via the Internet at http://pubs.acs.org.

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Notes

The authors declare no competing financial interest.

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